Video Difference Amplifier

FEATURES

- Differential or Single-Ended Gain Block (Adjustable)
- –3dB Bandwidth, A_V = ±2: 80MHz
- Slew Rate: 500V/µs
- Low Cost
- Output Current: ±50mA
- Settling Time: 180ns to 0.1%
- CMRR at 10MHz: >40dB
- Differential Gain Error: 0.2%
- Differential Phase Error: 0.08°
- Single 5V Operation
- Drives Cables Directly
- Output Shutdown

APPLICATIONS

- Line Receivers
- Video Signal Processing
- Cable Drivers
- Oscillators
- Tape and Disc Drive Systems

DESCRIPTION

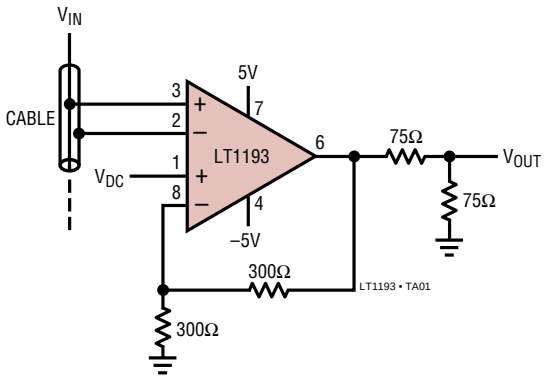
The LT®1193 is a video difference amplifier optimized for operation on ±5V and a single 5V supply. This versatile amplifier features uncommitted high input impedance (+) and (–) inputs, and can be used in differential or single-ended configurations. Additionally, a second set of inputs give gain adjustment and DC control to the differential amplifier.

The LT1193's high slew rate, 500V/µs, wide bandwidth, 80MHz, and ±50mA output current make it ideal for driving cables directly. The shutdown feature reduces the power dissipation to a mere 15mW and allows multiple amplifiers to drive the same cable.

The LT1193 is available in 8-pin PDIP and SO packages.

TYPICAL APPLICATION

Cable Sense Amplifier for Loop Through Connections with DC Adjust

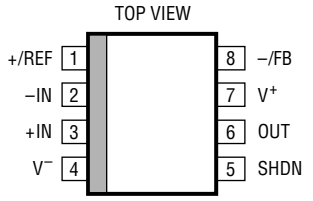


ABSOLUTE MAXIMUM RATINGS

(Note 1)

Total Supply Voltage (V^+ to V^-) 18V
Differential Input Voltage ..... ±6V
Input Voltage ..... $\pm V_S$
Output Short-Circuit Duration (Note 2) ..... Continuous
Operating Temperature Range
LT1193M **(OBSOLETE)** ..... –55°C to 125°C
LT1193C ..... 0°C to 70°C
LT1193I ..... –40°C to 85°C
Maximum Temperature ..... 150°C
Storage Temperature Range ..... –65°C to 150°C
Lead Temperature (Soldering, 10 sec) ..... 300°C

PACKAGE/ORDER INFORMATION



N8 PACKAGE
8-LEAD PDIP

S8 PACKAGE
8-LEAD PLASTIC SO

T_{JMAX} = 150°C, θ_{JA} = 100°C/W (N8)
T_{JMAX} = 150°C, θ_{JA} = 150°C/W (S8)

J8 PACKAGE 8-LEAD CERDIP
T_{JMAX} = 150°C, θ_{JA} = 100°C/W

ORDER PART NUMBER
LT1193CN8 LT1193CS8 LT1193IS8
S8 PART MARKING
1193 1193I
LT1193MJ8 LT1193CJ8

OBSOLETE PACKAGE
Consider the N8 or S8 Packages for Alternate Source

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

V_S = ±5V, V_{REF} = 0V, R_{FB1} = 900Ω from Pins 6 to 8, R_{FB2} = 100Ω from Pin 8 to ground, $R_L = R_{FB1} + R_{FB2}$ = 1k (Note 3), T_A = 25°C, $C_L \leq$ 10pF, Pin 5 open circuit, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	LT1193M/C/I MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	Both Inputs (Note 4) All Packages		2	12	mV
I_{OS}	Input Offset Current	Either Input		0.2	3	µA
I_B	Input Bias Current	Either Input		±0.5	±3.5	µA
e_n	Input Noise Voltage	f_O = 10kHz		50		nV/√Hz
i_n	Input Noise Current	f_O = 10kHz		4		pA/√Hz
R_{IN}	Input Resistance	Either Input		100		kΩ
C_{IN}	Input Capacitance	Either Input		2		pF
$V_{IN(LIM)}$	Input Voltage Limit	(Note 5)		1.3		V
	Input Voltage Range		–2.5		3.5	V
CMRR	Common Mode Rejection Ratio	V_{CM} = – 2.5V to 3.5V	60	75		dB
PSRR	Power Supply Rejection Ratio	V_S = ±2.375V to ±8V	60	75		dB
V_{OUT}	Output Voltage Swing	V_S = ±5V, R_L = 1k V_S = ±8V, R_L = 1k V_S = ±8V, R_L = 100Ω	±3.8 ±6.8 6.4	±4 ±7 6.6		V V V
G_E	Gain Error	V_O = ±3V, R_L = 1k R_L = 100Ω		0.1 0.1	1.0 1.2	% %
SR	Slew Rate	V_O = ±2V, R_L = 300Ω (Notes 6, 11)	350	500		V/µs
FPBW	Full-Power Bandwidth	V_O = $6V_{P-P}$ (Note 7)	18.5	26.5		MHz
BW	Small-Signal Bandwidth			9		MHz
t_r, t_f	Rise Time, Fall Time	A_V = 50, V_O = ±1.5V, 20% to 80% (Note 11)	110	160	210	ns
t_{PD}	Propagation Delay	R_L= 1k, V_O = ±125mV, 50% to 50%		15		ns
	Overshoot	V_O = ±50mV		0		%
t_s	Settling Time	3V Step, 0.1% (Note 8)		180		ns
Diff A_V	Differential Gain	R_L = 150Ω, A_V = 2 (Note 9)		0.2		%
Diff Ph	Differential Phase	R_L = 150Ω, A_V = 2 (Note 9)		0.08		Deg_{P-P}

ELECTRICAL CHARACTERISTICS

$V_S = \pm 5V$, $V_{REF} = 0V$, $R_{FB1} = 900\Omega$ from Pins 6 to 8, $R_{FB2} = 100\Omega$ from Pin 8 to ground, $R_L = R_{FB1} + R_{FB2} = 1k$ (Note 3), $T_A = 25°C$, $C_L \leq 10pF$, Pin 5 open circuit, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	LT1193M/C/I MIN	TYP	MAX	UNITS
I_S	Supply Current			35	43	mA
	Shutdown Supply Current	Pin 5 at V^-		1.3	2	mA
I_{SHDN}	Shutdown Pin Current	Pin 5 at V^-		20	50	µA
t_{ON}	Turn On Time	Pin 5 from V^- to Ground, $R_L = 1k$		300		ns
t_{OFF}	Turn Off Time	Pin 5 from Ground to V^-, $R_L = 1k$		200		ns

$V_S^+ = 5V$, $V_S^- = 0V$, $V_{REF} = 2.5V$, $R_{FB1} = 900\Omega$ from Pins 6 to 8, $R_{FB2} = 100\Omega$ from Pin 8 to V_{REF}, $R_L = R_{FB1} + R_{FB2} = 1k$ (Note 3), $T_A = 25°C$, $C_L \leq 10pF$, Pin 5 open circuit, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		LT1193M/C/I MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	Both Inputs (Note 4) All Packages			3	15	mV
I_{OS}	Input Offset Current	Either Input			0.2	3	µA
I_B	Input Bias Current	Either Input			±0.5	±3.5	µA
	Input Voltage Range			2		3.5	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = 2V$ to 3.5V		55	70		dB
V_{OUT}	Output Voltage Swing	$R_L = 100\Omega$ to Ground	V_{OUT} High	3.6	3.8		V
			V_{OUT} Low		0.25	0.4	V
SR	Slew Rate	$V_O = 1V$ to 3V			250		V/µs
BW	Small-Signal Bandwidth				8		MHz
I_S	Supply Current				32	40	mA
	Shutdown Supply Current	Pin 5 at V^-			1.3	2	mA
I_{SHDN}	Shutdown Pin Current	Pin 5 at V^-			20	50	µA

The ● denotes the specificatons which apply over the full operating temperature range of $-55°C \leq T_A \leq 125°C$. $V_S = \pm 5V$, $V_{REF} = 0V$, $R_{FB1} = 900\Omega$ from Pins 6 to 8, $R_{FB2} = 100\Omega$ from Pin 8 to ground, $R_L = R_{FB2} = 1k$ (Note 3), $C_L \leq 10pF$, Pin 5 open circuit, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		LT1193M MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage		●		2	16	mV
$\Delta V_{OS}/\Delta T$	Input V_{OS} Drift		●		20		µV/°C
I_{OS}	Input Offset Current		●		0.8	5	µA
I_B	Input Bias Current		●		±1	±5.5	µA
	Input Voltage Range		●	–2.5		3.5	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = -2.5V$ to 3.5V	●	53	70		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2.375V$ to $\pm 5V$	●	53	70		dB
V_{OUT}	Output Voltage Swing	$R_L = 1k$	●	3.6	4		V
		$V_S = \pm 8V$, $R_L = 100\Omega$	●	6	6.5		
G_E	Gain Error	$V_O = \pm 3V$, $R_L = 1k$	●		0.2	1.2	%
I_S	Supply Current		●		35	43	mA
	Shutdown Supply Current	Pin 5 at V^- (Note 10)	●		1.3	2.2	mA
I_{SHDN}	Shutdown Pin Current	Pin 5 at V^-	●		20		µA

ELECTRICAL CHARACTERISTICS

The ● denotes the specificatons which apply over the full operating temperature range of –40°C ≤ T_A ≤ 85°C. V_S = ±5V, V_{REF} = 0V, R_{FB1} = 900Ω from Pins 6 to 8, R_{FB2} = 100Ω from Pin 8 to ground, R_L = R_{FB2} = 1k (Note 3), C_L ≤ 10pF, Pin 5 open circuit, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		LT1193I MIN	LT1193I TYP	LT1193I MAX	UNITS
V_{OS}	Input Offset Voltage	SO-8 Package	●		2	20	mV
$\Delta V_{OS}/\Delta T$	Input V_{OS} Drift		●		20		µV/°C
I_{OS}	Input Offset Current		●		0.8	5	µA
I_B	Input Bias Current		●		±1	±5.5	µA
	Input Voltage Range		●	–2.5		3.5	V
CMRR	Common Mode Rejection Ratio	V_{CM} = –2.5V to 3.5V	●	53	70		dB
PSRR	Power Supply Rejection Ratio	V_S = ±2.375V to ±5V	●	53	70		dB
V_{OUT}	Output Voltage Swing	R_L = 1k	●	3.6	4		V
		V_S = ±8V, R_L = 100Ω	●	6	6.5		
G_E	Gain Error	V_O = ±3V, R_L = 1k	●		0.2	1.2	%
I_S	Supply Current		●		35	43	mA
	Shutdown Supply Current	Pin 5 at V^- (Note 10)	●		1.3	2.2	mA
I_{SHDN}	Shutdown Pin Current	Pin 5 at V^-	●		20		µA

The ● denotes the specificatons which apply over the full operating temperature range of 0°C ≤ T_A ≤ 70°C. V_S = ±5V, V_{REF} = 0V, R_{FB1} = 900Ω from Pins 6 to 8, R_{FB2} = 100Ω from Pin 8 to ground, R_L = R_{FB1} + R_{FB2} = 1k (Note 3), C_L ≤ 10pF, Pin 5 open circuit, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		LT1193C MIN	LT1193C TYP	LT1193C MAX	UNITS
V_{OS}	Input Offset Voltage	N8 Package SO-8 Package	● ●		2	14 20	mV mV
$\Delta V_{OS}/\Delta T$	Input V_{OS} Drift		●		20		µV/°C
I_{OS}	Input Offset Current		●		0.2	3.5	µA
I_B	Input Bias Current		●		±0.5	±4	µA
	Input Voltage Range		●	–2.5		3.5	V
CMRR	Common Mode Rejection Ratio	V_{CM} = –2.5V to 3.5V	●	55	70		dB
PSRR	Power Supply Rejection Ratio	V_S = ±2.375V to ±5V	●	55	70		dB
V_{OUT}	Output Voltage Swing	R_L = 1k R_L = 100Ω	● ●	3.7 6.2	4 6.6		V V
G_E	Gain Error	V_O = ±3V, R_L = 1k	●		0.2	1.2	%
I_S	Supply Current		●		35	43	mA
	Shutdown Supply Current	Pin 5 at V^- (Note 10)	●		1.3	2.1	mA
I_{SHDN}	Shutdown Pin Current	Pin 5 at V^-	●		20		µA

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: A heat sink is required to keep the junction temperature below absolute maximum when the output is shorted.

Note 3: When R_L = 1k is specified, the load resistor is R_{FB1} + R_{FB2}, but when R_L = 100Ω is specified, then an additional 100Ω is added to the output.

Note 4: V_{OS} measured at the output (Pin 6) is the contribution from both input pair, and is input referred.

Note 5: $V_{IN\ LIM}$ is the maximum voltage between $–V_{IN}$ and $+V_{IN}$ (Pin 2 and Pin 3) for which the output can respond.

Note 6: Slew rate is measured between ±2V on the output, with a ±1V input step, A_V = 3.

Note 7: Full-power bandwidth is calculated from the slew rate measurement:

FPBW = SR/2πV_P.

Note 8: Settling time measurement techniques are shown in "Take the Guesswork Out of Settling Time Measurements," EDN, September 19, 1985.

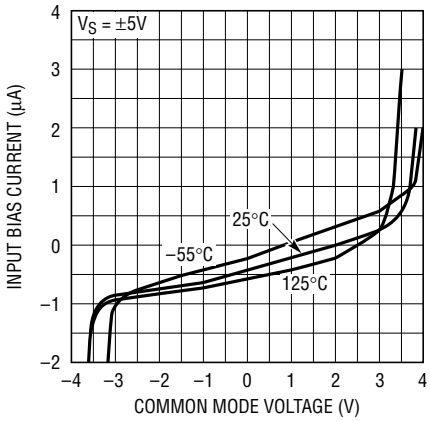
Note 9: NTSC (3.58MHz).

Note 10: See Applications section for shutdown at elevated temperatures. Do not operate the shutdown above T_J > 125°C.

Note 11: AC parameters are 100% tested on the ceramic and plastic DIP packaged parts (J and N suffix) and are sample tested on every lot of the SO packaged parts (S suffix).

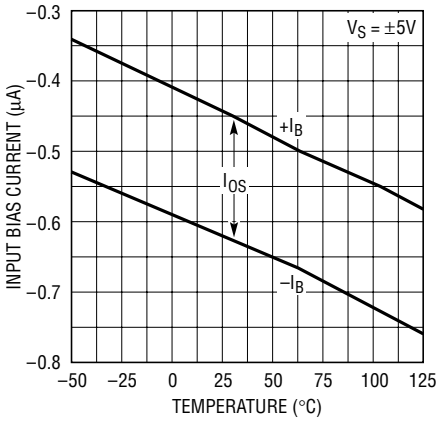
TYPICAL PERFORMANCE CHARACTERISTICS

Input Bias Current vs Common Mode Voltage



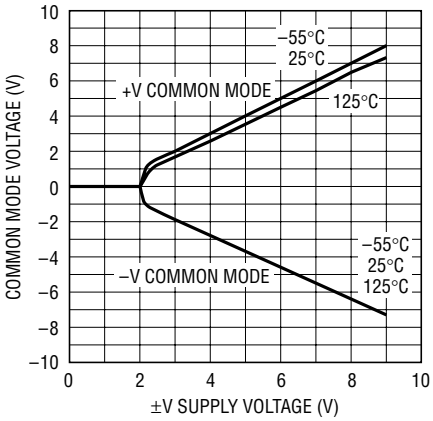
LT1193 • TPC01

Input Bias Current vs Temperature



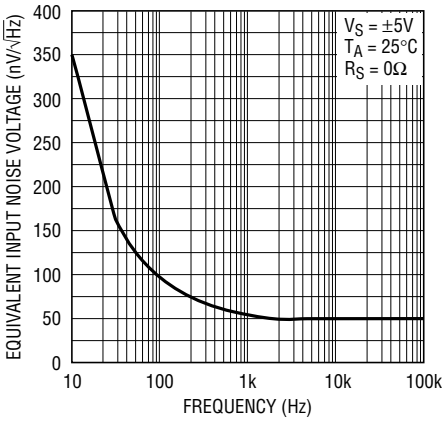
LT1193 • TPC02

Common Mode Voltage vs Supply Voltage



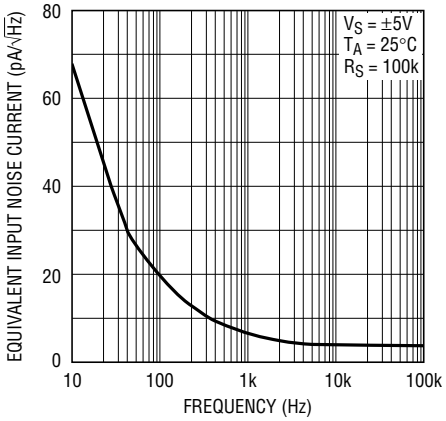
LT1193 • TPC03

Equivalent Input Noise Voltage vs Frequency



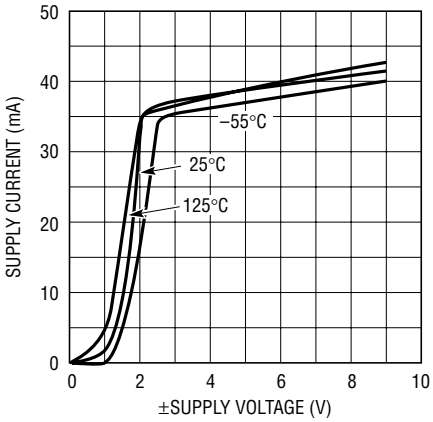
LT1193 • TPC04

Equivalent Input Noise Current vs Frequency



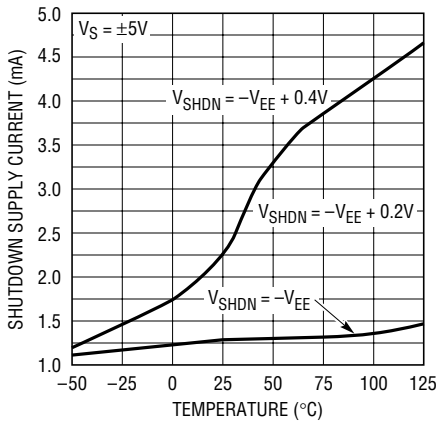
LT1193 • TPC05

Supply Current vs Supply Voltage



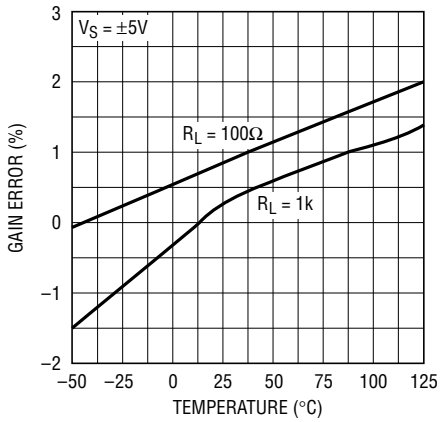
LT1193 • TPC06

Shutdown Supply Current vs Temperature



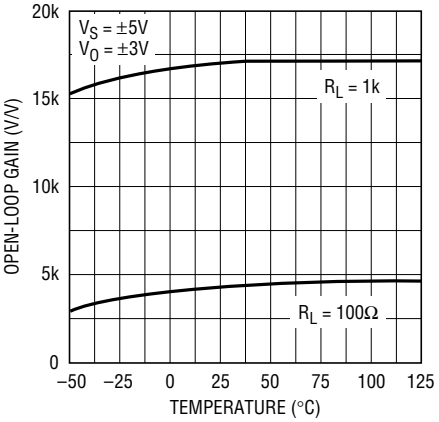
LT1193 • TPC07

Gain Error vs Temperature



LT1193 • TPC08

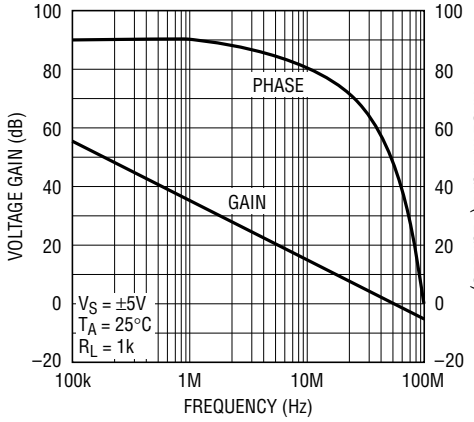
Open-Loop Gain vs Temperature



LT1193 • TPC09

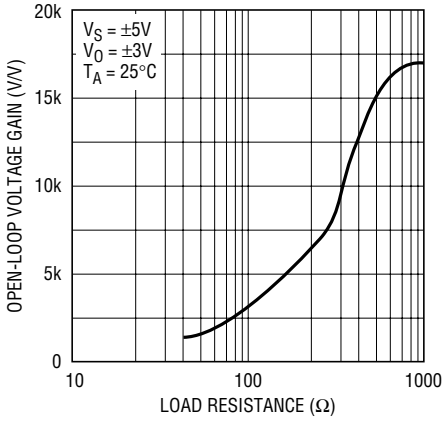
TYPICAL PERFORMANCE CHARACTERISTICS

Gain, Phase vs Frequency



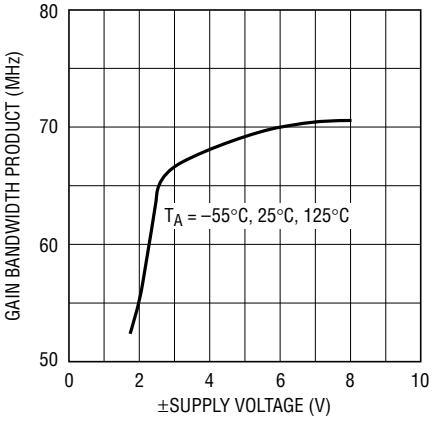
LT1193 • TPC11

Open-Loop Voltage Gain vs Load Resistance



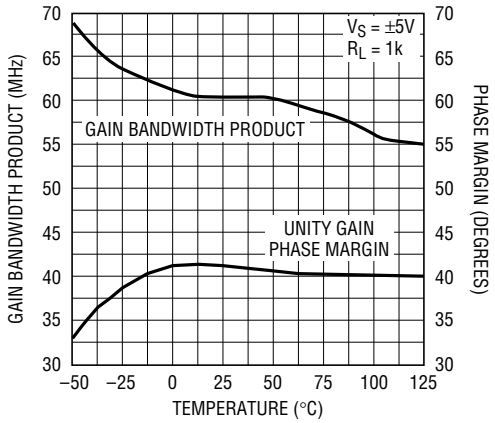
LT1193 • TPC10

Gain Bandwidth Product vs Supply Voltage



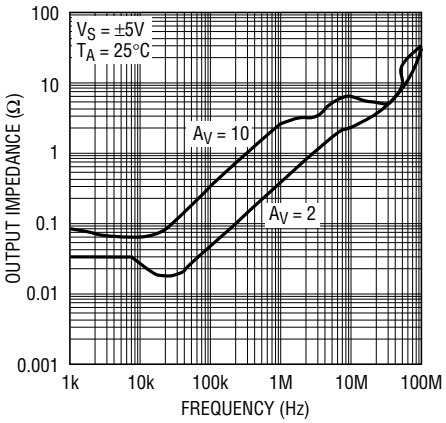
LT1193 • TPC12

Gain Bandwidth Product and Unity Gain Phase Margin vs Temperature



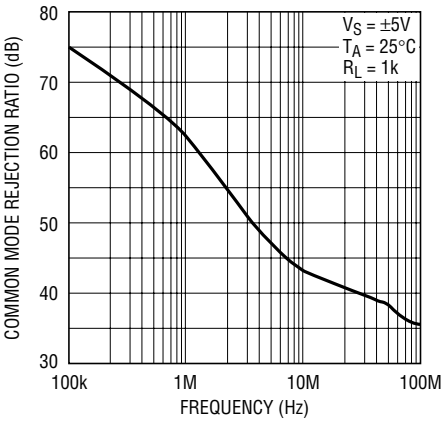
LT1193 • TPC13

Output Impedance vs Frequency



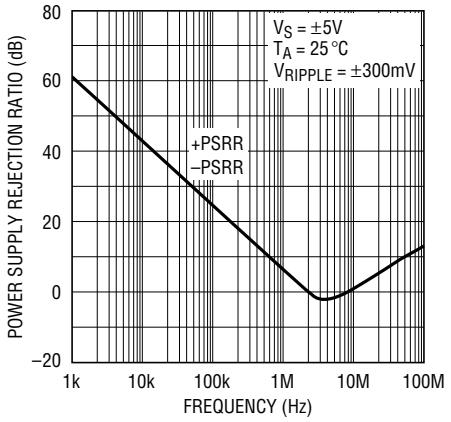
LT1193 • TPC14

Common Mode Rejection Ratio vs Frequency



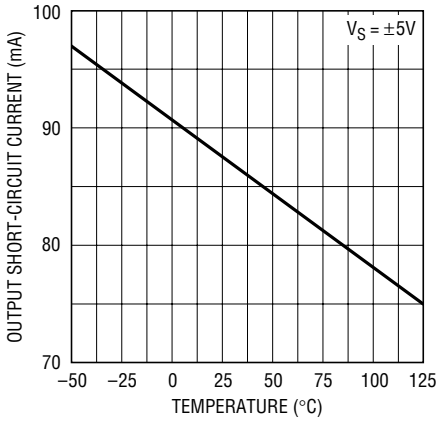
LT1193 • TPC15

Power Supply Rejection Ratio vs Frequency



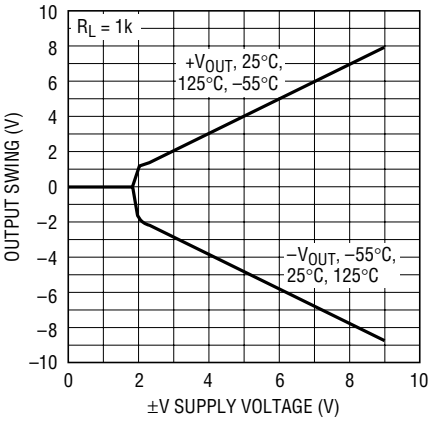
LT1193 • TPC16

Output Short-Circuit Current vs Temperature



LT1193 • TPC17

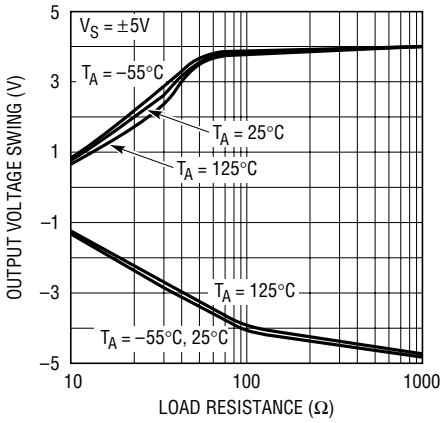
Output Swing vs Supply Voltage



LT1193 • TPC18

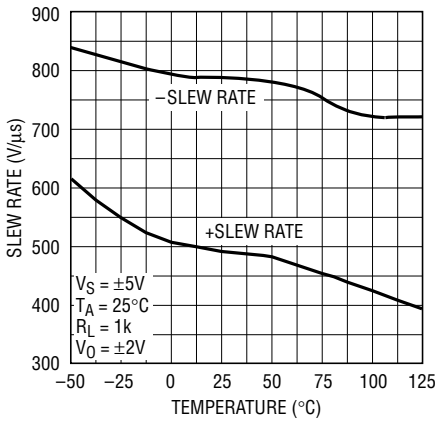
TYPICAL PERFORMANCE CHARACTERISTICS

Output Voltage Swing vs Load Resistance



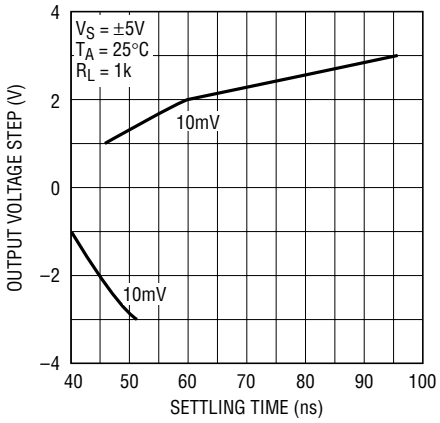
LT1193 • TPC19

Slew Rate vs Temperature



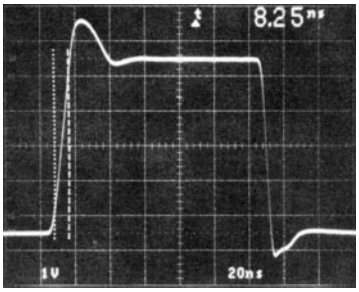
LT1193 • TPC20

Output Voltage Step vs Settling Time, A_V = 2



LT1193 • TPC21

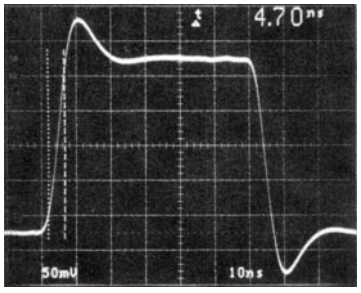
Large-Signal Transient Response



LT1193 • TPC22

A_V = 2, R_L = 150Ω, R_{FB} = 300Ω, R_G = 300Ω

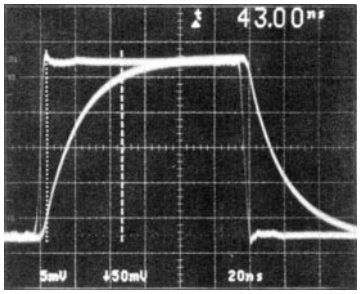
Small-Signal Transient Response



LT1193 • TPC23

A_V = –10, SMALL-SIGNAL RISE TIME = 43ns

Small-Signal Transient Response



LT1193 • TPC24

A_V = 2, R_{FB} = 300Ω, R_G = 300Ω,
OVERSHOOT = 25%, RISE TIME = 4.7ns

APPLICATIONS INFORMATION

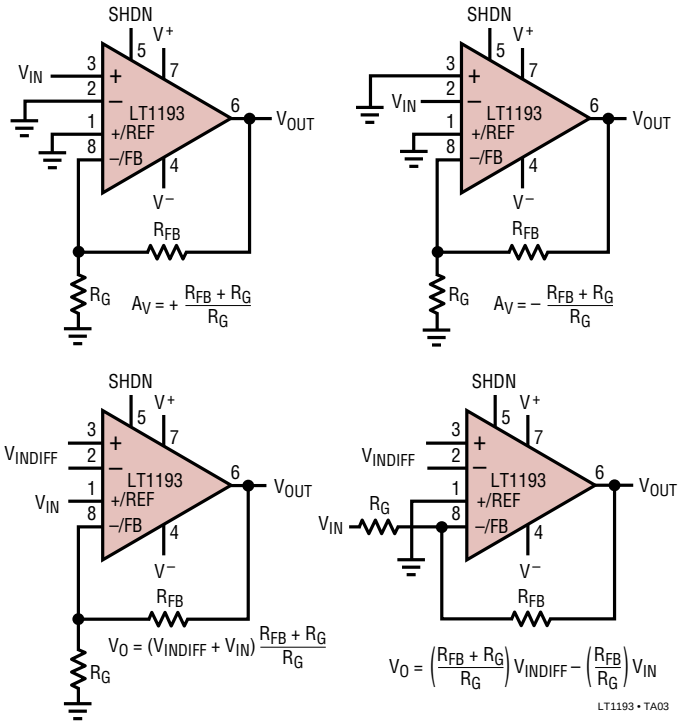
The LT1193 is a video difference amplifier which has two uncommitted high input impedance (+) and (–) inputs. The amplifier has one set of inputs that can be used for reference and feedback. Additionally, this set of inputs give gain adjust and DC control to the differential amplifier. The voltage gain of the LT1193 is set like a conventional operational amplifier. Feedback is applied to Pin 8 and it is optimized for gains of 2 or greater. The amplifier can be operated single-ended by connecting either the (+) or (–) inputs to +/REF, Pin 1. The voltage gain is set by the resistors: $(R_{FB} + R_G)/R_G$.

The primary usefulness of the LT1193 is in converting high speed differential signals to a single-ended output. The amplifier has common mode rejection beyond 50MHz and a full-power bandwidth of 40MHz at $4V_{P-P}$. Like the single-ended case, the differential voltage gain is set by the external resistors: $(R_{FB} + R_G)/R_G$. The maximum input differential signal for which the output will respond is approximately ±1.3V.

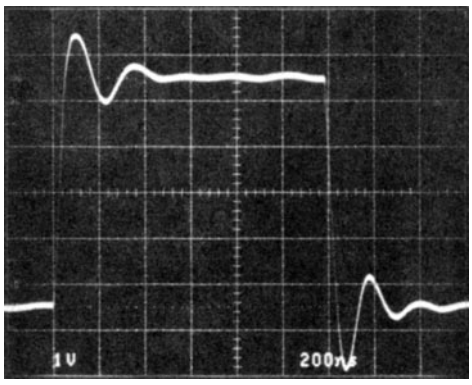
Power Supply Bypassing

The LT1193 is quite tolerant of power supply bypassing. In some applications a 0.1µF ceramic disc capacitor placed 1/2 inch from the amplifier is all that is required. A scope photo of the amplifier output with no supply bypassing is used to demonstrate this bypassing tolerance, R_L = 1k.

APPLICATIONS INFORMATION



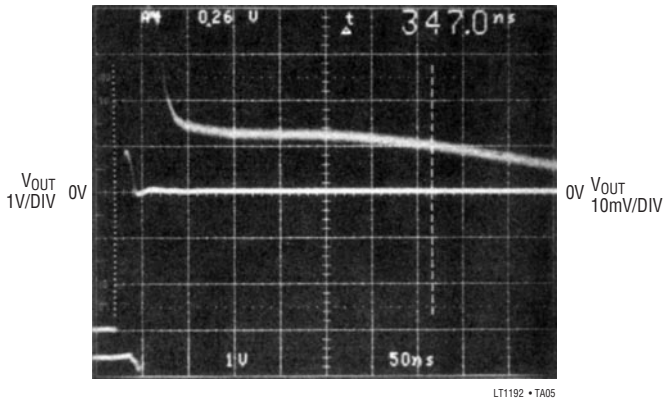
No Supply Bypass Capacitors



A_V = 10, IN DEMO BOARD, R_L = 1k

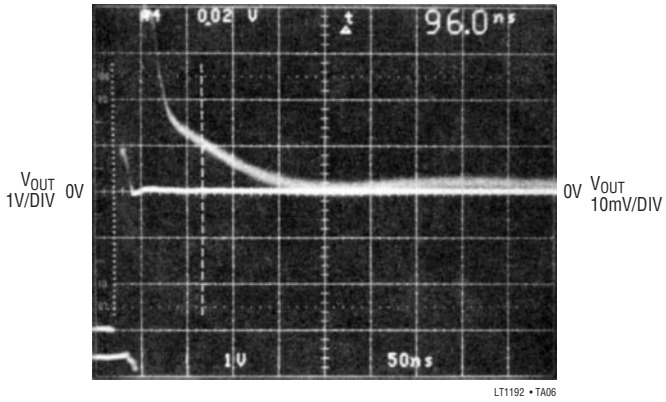
In many applications and those requiring good settling time it is important to use multiple bypass capacitors. A 0.1µF ceramic disc in parallel with a 4.7µF tantalum is recommended. Two oscilloscope photos with different bypass conditions are used to illustrate the settling time characteristics of the amplifier. Note that although the output waveform looks acceptable at 1V/DIV, when amplified to 10mV/DIV the settling time to 10mV is 347ns for the 0.1µF bypass; the time drops to 96ns with multiple bypass capacitors.

Settling Time Poor Bypass



SETTLING TIME TO 10mV, A_V = 2
SUPPLY BYPASS CAPACITORS = 0.1µF

Settling Time Good Bypass



SETTLING TIME TO 10mV, A_V = 2
SUPPLY BYPASS CAPACITORS = 0.1µF + 4.7µF TANTALUM

Operating With Low Closed-Loop Gains

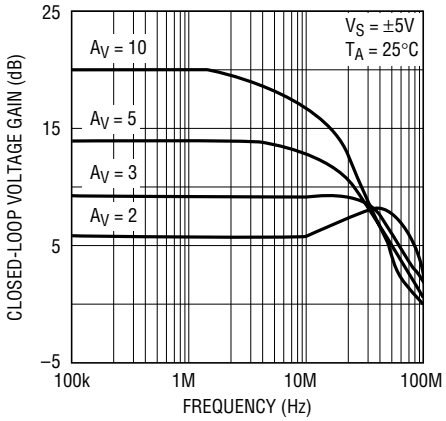
The LT1193 has been optimized for closed-loop gains of 2 or greater; the frequency response illustrates the obtainable closed-loop bandwidths. For a closed-loop gain of 2 the response peaks about 2dB. Peaking can be minimized by keeping the feedback elements below 1kΩ, and can be eliminated by placing a capacitor across the feedback resistor, (feedback zero). This peaking shows up as time domain overshoot of about 40%. With the feedback capacitor it is eliminated.

Cable Terminations

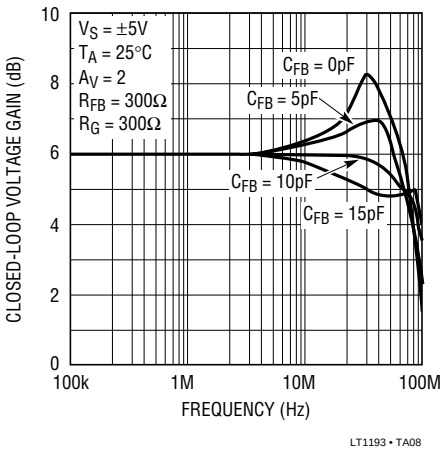
The LT1193 video difference amplifier has been optimized as a low cost cable driver. The ±50mA guaranteed output current enables the LT1193 to easily deliver 7.5V_{P-P} into

APPLICATIONS INFORMATION

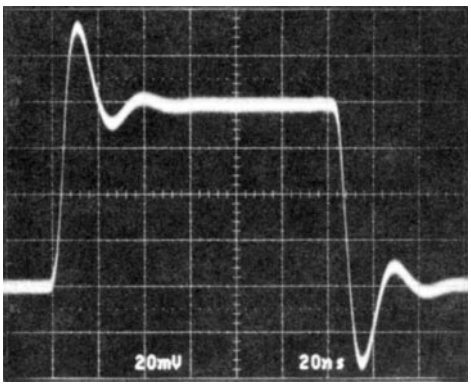
Closed-Loop Voltage Gain vs Frequency



Closed-Loop Voltage Gain vs Frequency



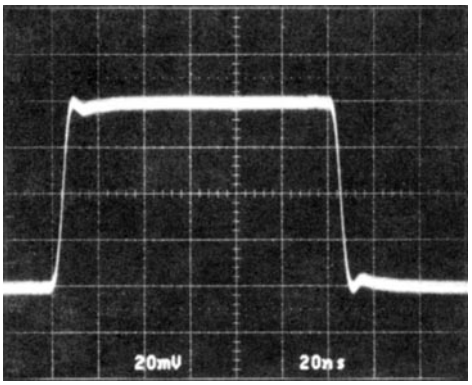
Small-Signal Transient Response



AV = 2, OVERSHOOT = 40%, RFB = 1k, RG = 1k

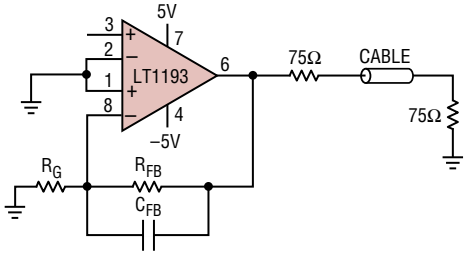
100Ω, while operating on ±5V supplies and gains >3. On a single 5V supply, the LT1193 can swing 2.6V_{P-P} for gains ≥2.

Small-Signal Transient Response

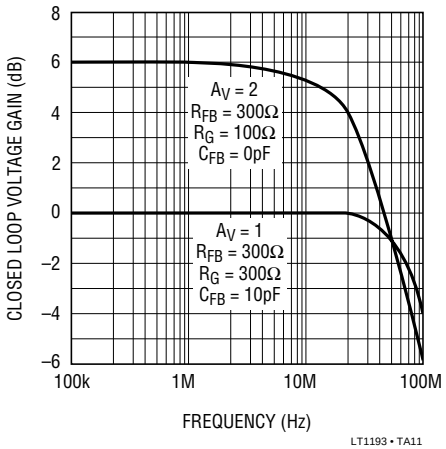


AV = 2 WITH 8pF FEEDBACK CAPACITOR
RISE TIME = 3.75ns, RFB = 1k, RG = 1k

Double Terminated Cable Driver



Closed-Loop Voltage Gain vs Frequency



When driving a cable it is important to terminate the cable to avoid unwanted reflections. This can be done in one of two ways: single termination or double termination. With single termination, the cable must be terminated at the receiving end (75Ω to ground) to absorb unwanted energy. The best performance can be obtained by double termination (75Ω in series with the output of the amplifier, and 75Ω to ground at the other end of the cable). This

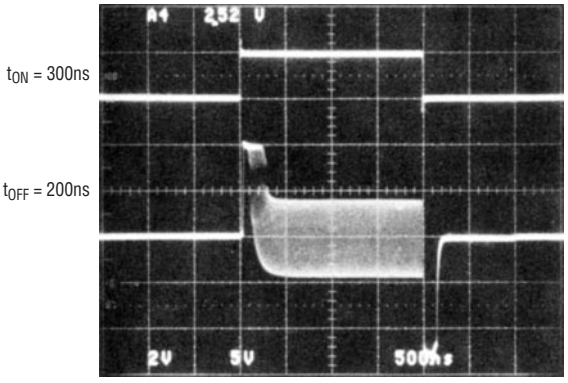
APPLICATIONS INFORMATION

termination is preferred because reflected energy is absorbed at each end of the cable. When using the double termination technique it is important to note that the signal is attenuated by a factor of 2, or 6dB. The cable driver has a –3dB bandwidth of 80MHz while driving a 150Ω load.

Using the Shutdown Feature

The LT1193 has a unique feature that allows the amplifier to be shut down for conserving power or for multiplexing several amplifiers onto a common cable. The amplifier will shut down by taking Pin 5 to V^-. In shutdown, the amplifier dissipates 15mW while maintaining a true high impedance output state of 15kΩ in parallel with the feedback resistors. The amplifiers may be connected inverting, noninverting or differential for MUX applications. When the output is loaded with as little as 1kΩ from the amplifier's feedback resistors, the amplifier shuts off in 200ns. This shutoff can be under the control of HC CMOS operating between 0V and –5V.

Output Shutdown



LT1193 • TA12

1MHz SINE WAVE GATED OFF WITH
SHUTDOWN PIN, A_V = 3, R_{FB} = 1k, R_G = 500Ω

The ability to maintain shutoff is shown on the curve Shutdown Supply Current vs Temperature in the Typical Performance Characteristics section. At very high elevated temperatures it is important to hold the SHDN pin close to the negative supply to keep the supply current from increasing.

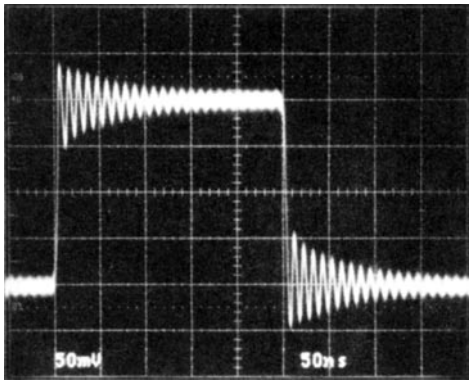
Murphy Circuits

There are several precautions the user should take when using the LT1193 in order to realize its full capability. Although the LT1193 can drive a 30pF in gains as low as 2, isolating the capacitance with 10Ω can be helpful. Precautions primarily have to do with driving large capacitive loads.

Other precautions include:

1. Use a ground plane (see Design Note 50, High Frequency Amplifier Evaluation Board).
2. Do not use high source impedances. The input capacitance of 2pF, and R_S = 10k for instance, will give an 8MHz –3dB bandwidth.
3. PC board socket may reduce stability.
4. A feedback resistor of 1k or lower reduces the effects of stray capacitance at the inverting input. (For instance, closed-loop gain of ±2 can use R_{FB} = 300Ω and R_G = 300Ω.)

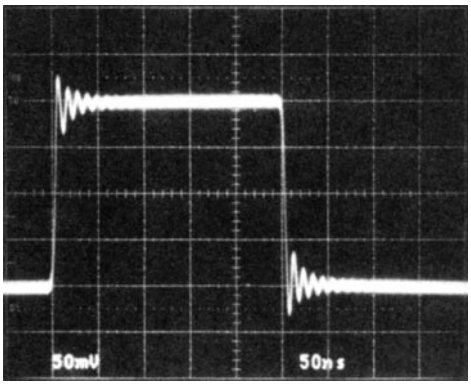
Driving Capacitive Load



LT1193 • TA14

A_V = 2, IN DEMO BOARD, C_L = 30pF, R_{FB} = 1k, R_G = 1k

Driving Capacitive Load

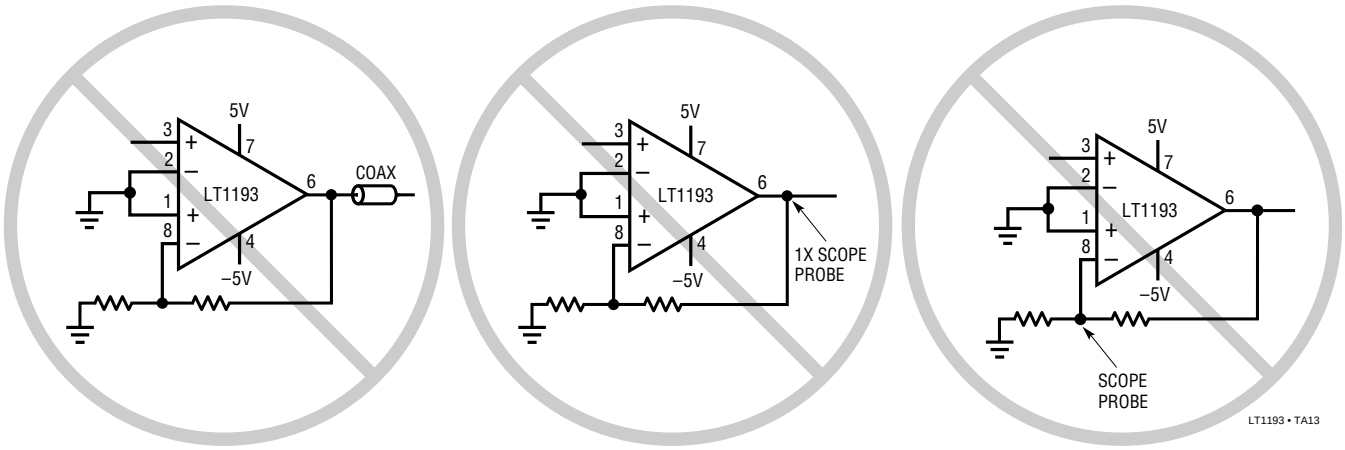


LT1193 • TA15

A_V = 2, IN DEMO BOARD, C_L = 30pF
WITH 10Ω ISOLATING RESISTOR

APPLICATIONS INFORMATION

Murphy Circuits

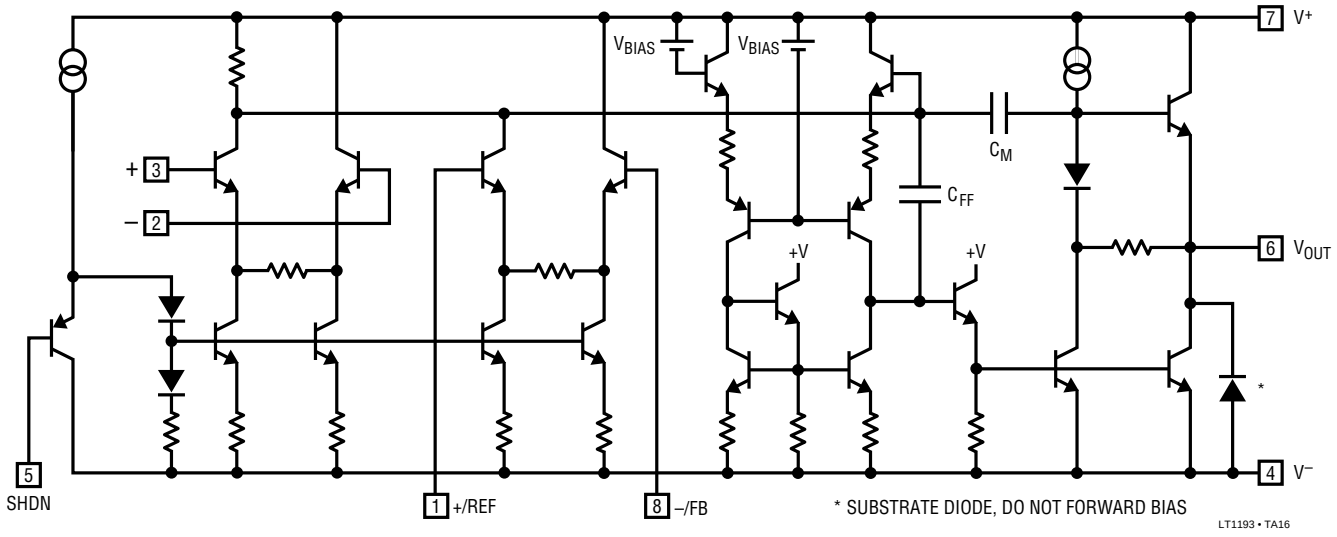


An Unterminated Cable Is a Large Capacitive Load

A 1X Scope Probe Is a Large Capacitive Load

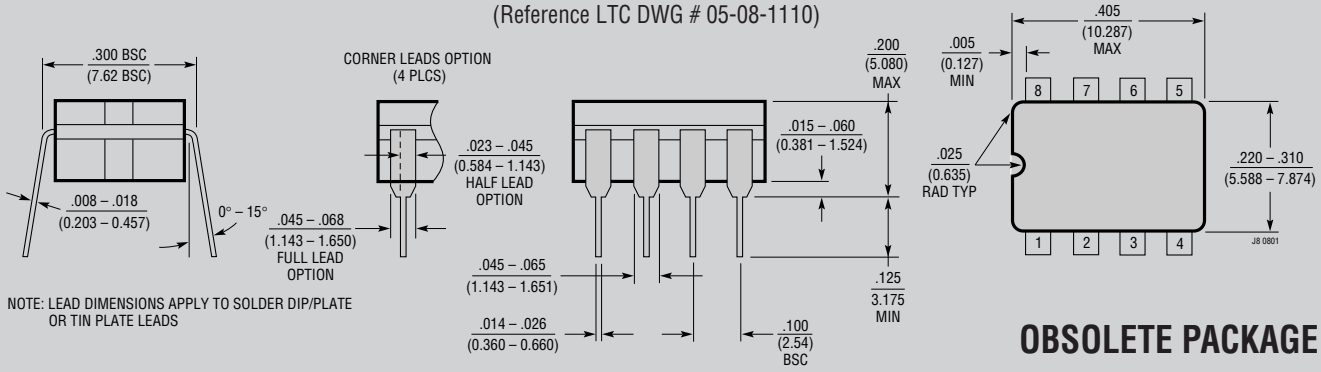
A Scope Probe on the Inverting Input Reduces Phase Margin

SIMPLIFIED SCHEMATIC



PACKAGE DESCRIPTION

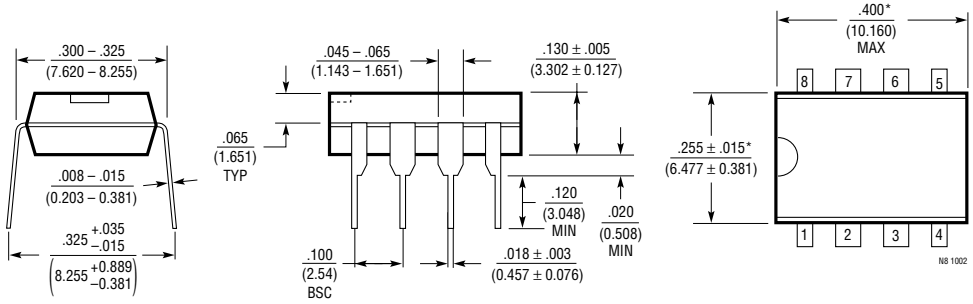
J8 Package
8-Lead CERDIP (Narrow .300 Inch, Hermetic)
(Reference LTC DWG # 05-08-1110)



NOTE: LEAD DIMENSIONS APPLY TO SOLDER DIP/PLATE OR TIN PLATE LEADS

OBSOLETE PACKAGE

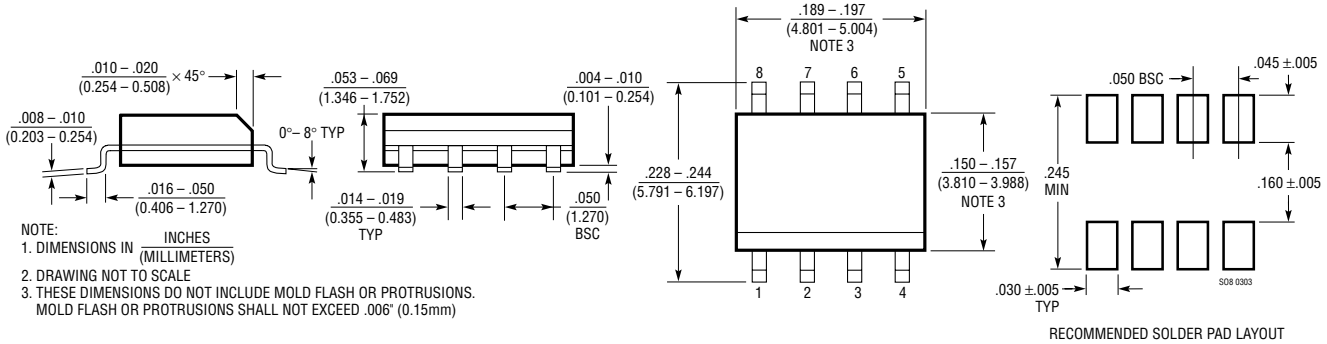
N8 Package
8-Lead PDIP (Narrow .300 Inch)
(Reference LTC DWG # 05-08-1510)



NOTE:
1. DIMENSIONS ARE INCHES / MILLIMETERS

*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 INCH (0.254mm)

S8 Package
8-Lead Plastic Small Outline (Narrow .150 Inch)
(Reference LTC DWG # 05-08-1610)



NOTE:
1. DIMENSIONS IN INCHES / (MILLIMETERS)
2. DRAWING NOT TO SCALE
3. THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .006" (0.15mm)

RECOMMENDED SOLDER PAD LAYOUT

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1194	Video Difference Amp	A_V = 10 Version of the LT1193

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